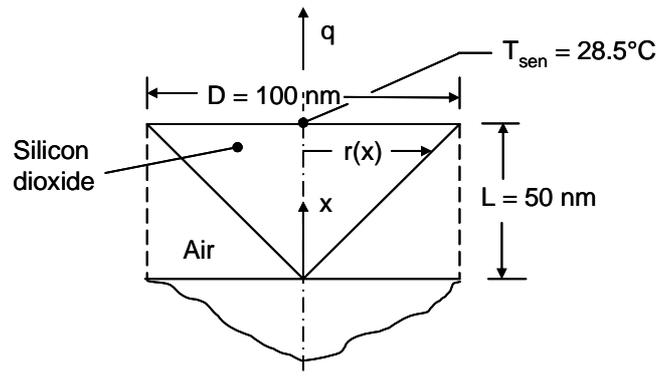


PROBLEM 3.44

KNOWN: Construction and dimensions of a device to measure the temperature of a surface. Ambient and sensing temperatures, and thermal resistance between the sensing element and the pivot point.

FIND: (a) Thermal resistance between the surface temperature and the sensing temperature, (b) Surface temperature for $T_{\text{sen}} = 28.5^\circ\text{C}$.

SCHEMATIC:



ASSUMPTIONS: (1) Steady-state conditions, (2) One-dimensional heat transfer, (3) Negligible nanoscale effects, (4) Constant properties.

PROPERTIES: Table A.2, polycrystalline silicon dioxide (300 K): $k = 1.38 \text{ W/m}\cdot\text{K}$. Table A.4, air (300 K): $k = 0.0263 \text{ W/m}\cdot\text{K}$.

ANALYSIS:

(a) At any x location, heat transfer in the x -direction occurs by conduction in the air as well as conduction in the probe. Applying Fourier's law,

$$q_x = -k_a A_a \frac{dT}{dx} - k_p A_p \frac{dT}{dx} \quad (1)$$

Since the probe radius is $r = Dx/2L$, the probe area is

$$A_p = \frac{\pi D^2}{4L^2} x^2 \quad \text{and} \quad A_a = \frac{\pi D^2}{4} - A_p = \frac{\pi D^2}{4} \left[1 - \frac{x^2}{L^2} \right] \quad (2a, 2b)$$

Substituting Eqs. (2a) and (2b) into Eq. (1) yields

$$q_x = -\frac{\pi D^2}{4L^2} \left[k_a (L^2 - x^2) + k_p x^2 \right] \frac{dT}{dx}$$

Separating variables and integrating,

Continued...

